

SILICON TRANSISTOR 2SB1628

PNP SILICON EPITAXIAL TRANSISTOR FOR LOW-FREQUENCY POWER AMPLIFIERS AND MID-SPEED SWITCHING

The 2SB1628 features high current capacity in small dimension and is ideal for DC/DC converters and mortor drivers.

FEATURES

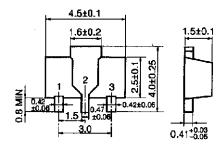
- · High current capacitance
- · Low collector saturation voltage

QUALITY GRADES

Standard

Please refer to "Quality Grades on NEC Semiconductor Devices" (Document No. C11531E) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

PACKAGE DRAWING (UNIT: mm)



Electrode connection

- 1: Emitter
- 2: Collector (fin)
- 3: Base

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Conditions	Ratings	Unit
Collector to base voltage	Vсво		-20	V
Collector to emitter voltage	VCEO		-16	V
Emitter to base voltage	VEBO		-6.0	V
Collector current (DC)	Ic(DC)		-3.0	Α
Collector current (pulse)	C(pulse)	PW ≤ 10 ms Duty cycle ≤ 50 %	-5.0	Α
Base current (DC)	I _{B(DC)}		-0.2	Α
Base current (pulse)	B(pulse)	PW ≤ 10 ms Duty cycle ≤ 50 %	-0.4	Α
Total power dissipation	Рт	$16 \text{ cm}^2 \times 0.7 \text{ mm}$ ceramic board used	2.0	W
Junction temperature	Tj		150	°C
Storage temperature	Tstg		-55 to +150	°C

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Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.



ELECTRICAL CHARACTERISTICS (Ta = 25°C)

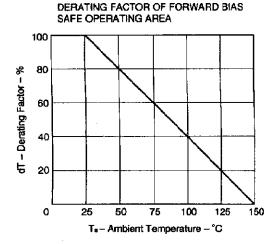
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	VcBo = -20 V, IE = 0			-100	nA
Emitter cutoff current	ІЕВО	VEBO = -6.0 V, Ic = 0			-100	nA
DC current gain	h _{FE1}	Vce = -2.0 V, Ic = -0.5 A	140	280	560	-
DC current gain	h _{FE2}	Vce = -2.0 V, Ic = -3.0 A	70			-
DC base voltage	VBE	Vce = -2.0 V, Ic = -0.05 A	-600	-660	-700	mV
Collector saturation voltage	VCE(sat)1	Ic = -2.0 A, I _B = -0.1 A		-240	-350	mV
Collector saturation voltage	VCE(sat)2	Ic = -3.0 A, Iв = -0.15 A		-350	-550	mV
Base saturation voltage	V _{BE(sat)}	Ic = -2.0 A, I _B = -0.1 A		-0.95	-1.2	٧
Gain bandwidth product	f⊤	Vce = -3.0 V, IE = 0.5 A		320		MHz
Output capacitance	Сор	VcB = −10 V, IE = 0, f = 1 MHz		45		pF
Turn-on time	ton	Ic = -1.0 A, Vcc = -10 V		70		ns
Storage time	t stg	$I_{B1} = -I_{B2} = -0.1 \text{ A}$ $R_L = 10 \Omega$		110		ns
Fall time	tf	111 - 10 22		40		ns

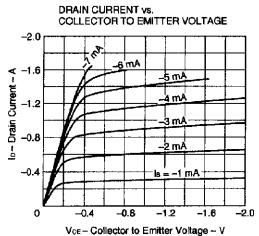
hfe CLASSIFICATION

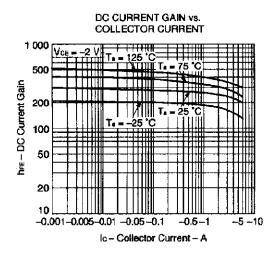
Marking	ZX	ZY	ZZ	
h _{FE1}	140 to 280	200 to 400	280 to 560	

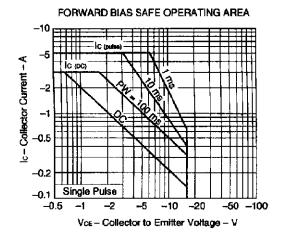


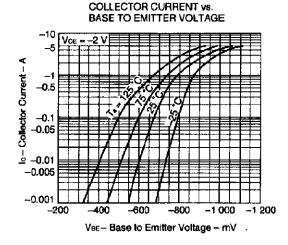
TYPICAL CHARACTERISTICS (Ta = 25°C)

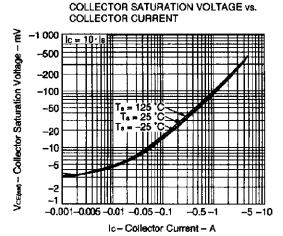




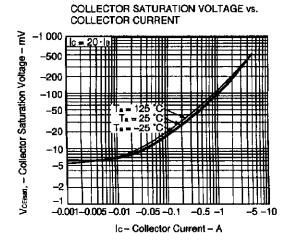


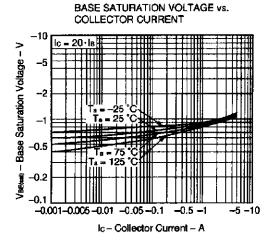


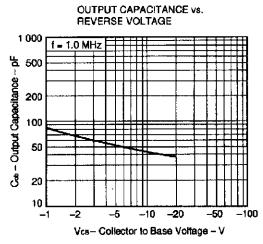


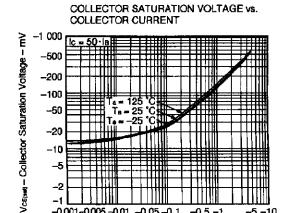


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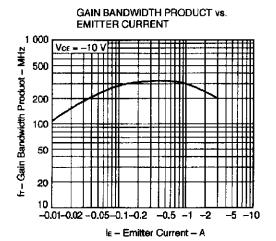








-0.001-0.005 -0.01

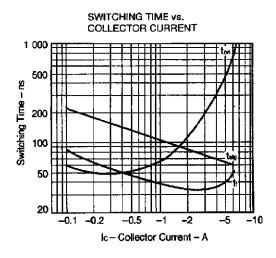


-0.05 - 0.1

lo-Collector Current - A

-0.5 - 1

-5 - 10





[MEMO]

- The information in this document is current as of July, 2001. The information is subject to change
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